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(ii) Questions : 7 Sub. Code : 0 4 4 9 Exam. Code : 0 0 0 5

B.A./B.Sc. (General) 5th Semester 1128 PHYSICS

Paper—B: Electronics and Solid State Devices—I

Time Allowed: Three Hours] [Maximum Marks: 22

- Note:— (1) Attempt *five* questions in all, selecting *two* questions from each of Unit-I and Unit-II.
 - (2) Unit-III is compulsory.
 - (3) Use of non-programmable calculator is allowed.

UNIT-I

- (a) Draw the block diagram of Cathode Ray Tube (CRT). What is the function of aquading coating necessary in (CRT)? Draw the pattern observed on the screen of the cathode ray oscilloscope, when the phase difference between two signals of same frequency is (i) 45° (ii) 180°.
 - (b) State Thevenin's theorem, explain with example. 11/2
- (a) Derive an expression for position of fermi level in an intrinsic semiconductor. How does its position change when acceptor atoms are added to a semiconductor?
 What happens if its temperature is raised?
 - (b) A N-type semiconductor made up of germanium has resistivity 4 Ω cm and electron mobility 3200 cm²/volt-sec. Find the donor concentration.

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- 3. (a) Explain principle and working of Light Emitting Diode (LED). Write any two applications of LED and explain why we prefer LEDs over conventional incandescent lamps.
 - (b) The reverse bias saturation current for PN junction diode is 2 μA at 300 K. Determine its dynamic resistance at 125 mV forward bias.

UNIT-II

- 4. (a) Draw the circuit diagram of LC filter with full wave rectifier. Explain its working. Also derive the expression for its ripple factor.
 - (b) Explain the working of voltage regulation circuit using zener diode. 1½
- (a) Draw the input and output characteristics of common emitter n-p-n transistor. Explain active, saturation and cut off regions.
 - (b) A transistor has $\alpha = 0.96$, leakage current 1.5 μ A and collector current 0.845 mA. Find the emitter current and base current in transistor.
- 6. (a) Define stability factor. Draw a collector to base bias circuit diagram and derive an expression for its stability factor. What are the disadvantages of this technique?
 - (b) A transistor in common base with $\alpha = 0.98$ gives reverse saturation current $I_{CBO} = 10 \mu A$. When used in CE mode, it gives the base current of 0.1 mA. Calculate its total collector current in CE mode.

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UNIT—III

- 7. Attempt any eight questions:
 - (i) What is the charge on n type semiconductor?
 - (ii) What is zener breakdown? What is its cause?
 - (iii) What is the negative clipper?
 - (iv) What do you understand by load line?
 - (v) What is the advantage of bridge rectifier over conventional full wave rectifier?
 - (vi) Describe the action of the inductor filter and its limitations.
 - (vii) Why BJT is called current controlled device?
 - (viii) Why is capacitor filter preferred than the inductor filter?
 - (ix) What is the leakage current in a transistor?
 - (x) Why is the width of the base regions of a transistor very small? $\frac{1}{2} \times 8 = 4$